



MACMIC

TM

October 2009

PRELIMINARY

MMF400Y040DK1

400V 400A DUTO FRED Module

RoHS Compliant

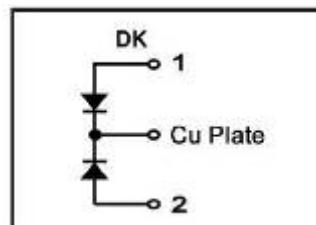
PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package



APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

T_C=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V _R	Maximum D.C. Reverse Voltage		400	V
V _{RRM}	Maximum Repetitive Reverse Voltage		400	V
I _{F(AV)}	Average Forward Current	T _C =125°C, Per Diode	200	A
		T _C =125°C, Per Moudle	400	A
		T _C =125°C, 20KHz, Per Moudle	300	A
I _{F(RMS)}	RMS Forward Current	T _C =125°C, Per Diode	282	A
I _{FSM}	Non-Repetitive Surge Forward Current	1/2 Cycle , 50Hz, Sine	4000	A
		1/2 Cycle , 60Hz, Sine	4500	A
I ² t	I ² t (For Fusing)	T _J =45°C, t=10ms, 50Hz, Sine	80000	A ² s
		T _J =45°C, t=8.3ms, 60Hz, Sine	101250	A ² s
P _D	Power Dissipation		2080	W
T _J	Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature Range		-40 to +125	°C
Torque	Module-to-Sink	Recommended (M6)	3~4.7	N·m
Torque	Module Electrodes	Recommended (M6)	3~4.7	N·m
R _{θJC}	Thermal Resistance	Junction-to-Case	0.06	°C /W
Weight			92	g

MacMic Science & Technology Co., Ltd.

Add: #18, Hua Shan Zhong Lu, New District, Changzhou City, Jiangsu Province, P. R .of China

Tel.: +86-519-85163708 Fax: +86-519-85162291 Post Code: 213022 Website: www.macmicst.com

ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R=400\text{V}$	--	--	1	mA
		$V_R=400\text{V}, T_J=125^\circ\text{C}$	--	--	2	mA
V_F	Forward Voltage	$I_F=200\text{A}$	--	1.1	1.35	V
		$I_F=200\text{A}, T_J=125^\circ\text{C}$	--	1.0	1.25	V
t_{rr}	Reverse Recovery Time	$I_F=1\text{A}, V_R=30\text{V}, di_F/dt=-200\text{A}/\mu\text{s}$	--	45	--	ns
t_{rr}	Reverse Recovery Time	$V_R=200\text{V}, I_F=200\text{A}$	--	135	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=25^\circ\text{C}$	--	12	--	A
t_{rr}	Reverse Recovery Time	$V_R=200\text{V}, I_F=200\text{A}$	--	210	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$	--	20	--	A

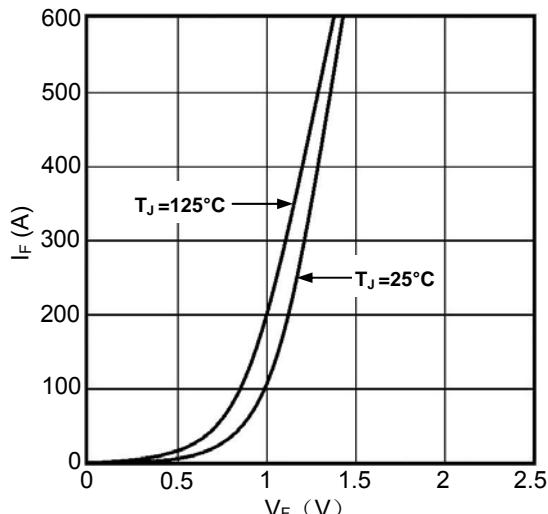
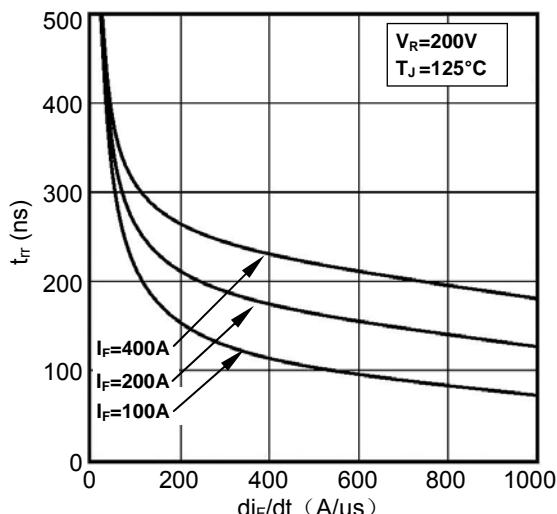
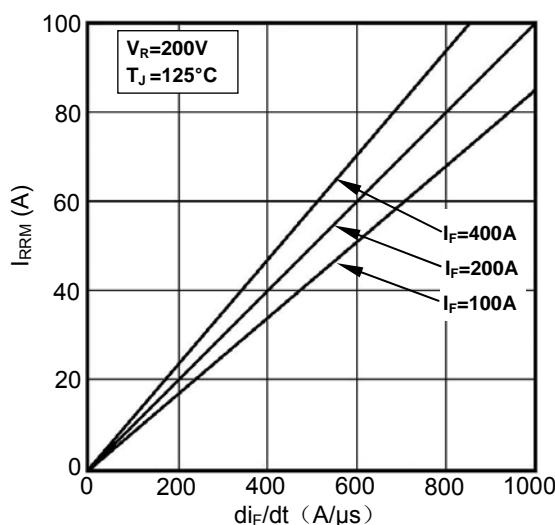
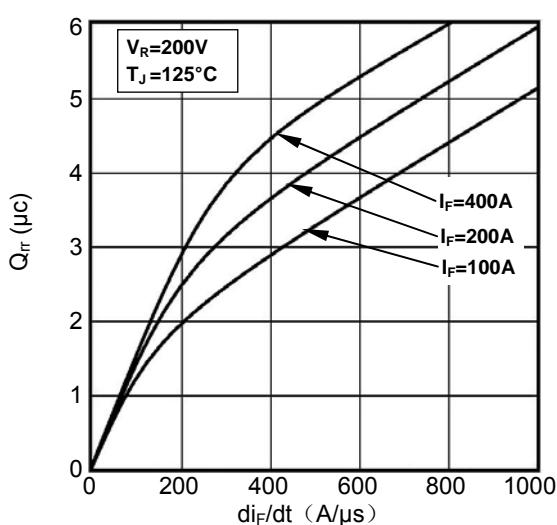


Figure1. Forward Voltage Drop vs Forward Current

Figure2. Reverse Recovery Time vs di_F/dt Figure3. Reverse Recovery Current vs di_F/dt Figure4. Reverse Recovery Charge vs di_F/dt

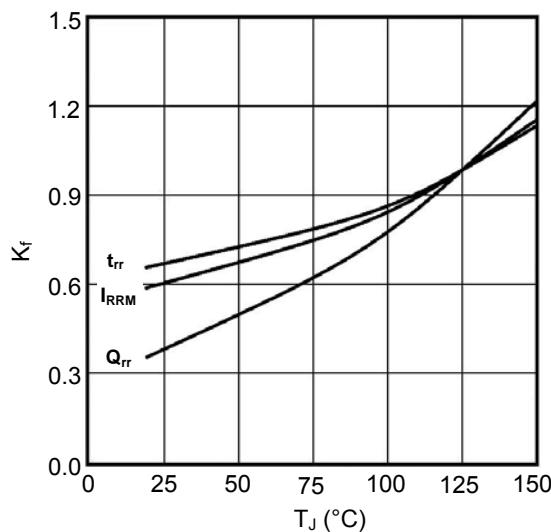


Figure 5. Dynamic Parameters vs Junction Temperature

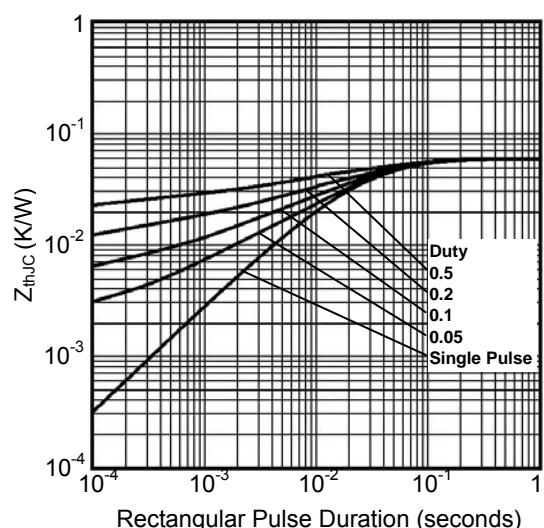
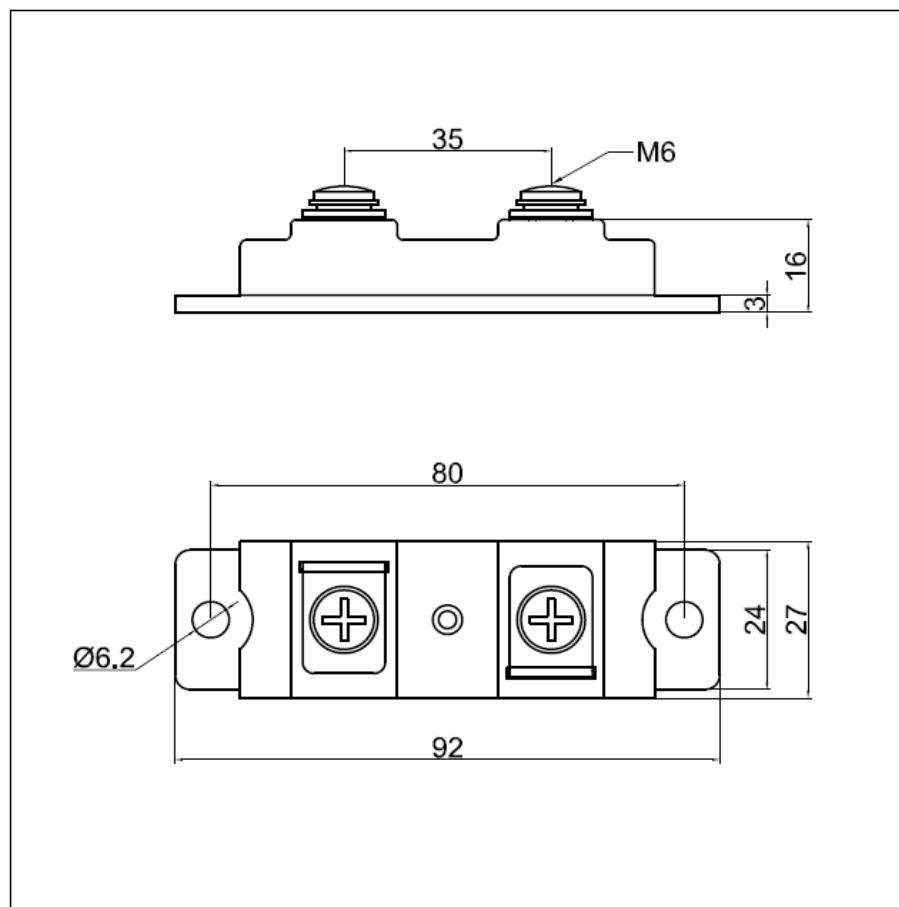


Figure 6. Transient Thermal Impedance



Dimensions (mm)
Figure 7. Package Outline